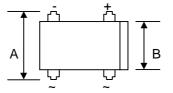
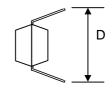
1.5A GLASS PASSIVATED BRIDGE RECTIFIER

Features

- Glass Passivated Die Construction
- Low Forward Voltage Drop
- High Current Capability
- High Surge Current Capability
- Designed for Surface Mount Application
- UL Recognized File #E157705





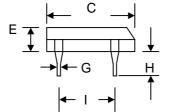
Mechanical Data

Case: Molded Plastic

 Terminals: Plated Leads Solderable per MIL-STD-202, Method 208

Polarity: As Marked on Case Weight: 0.38 grams (approx.)

Mounting Position: AnyMarking: Type Number



DIL						
Dim	Min	Max				
Α	7.40	7.90				
В	6.20	6.50				
С	8.13	8.51				
D	7.60	8.90				
Е	2.20	2.50				
G	0.41	0.51				
Н	3.90	4.20				
ı	5.0	5.20				
All Dimensions in mm						

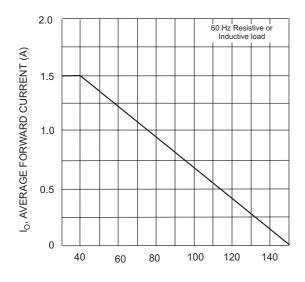
Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

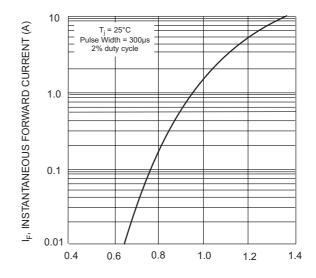
Characteristic	Symbol	DF150	DF151	DF152	DF154	DF156	DF158	DF1510	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRRM VRWM VR	50	100	200	400	600	800	1000	٧
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	560	700	٧
Average Rectified Output Current @T _A = 40	°C Io	1.5						Α	
Non-Repetitive Peak Forward Surge Current 8.3 Single half sine-wave superimposed on rated lo (JEDEC Method)		50					А		
Forward Voltage per element @I _F = 1.5	A VFM	1.1						V	
	I IRM	10 500					μΑ		
Typical Junction Capacitance per element (Note	- 1) Cj	25						pF	
Typical Thermal Resistance (Note 2)	$R_{ heta}JA$	40					K/W		
Operating and Storage Temperature Range	Tj, Tstg	-55 to +150					°C		

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

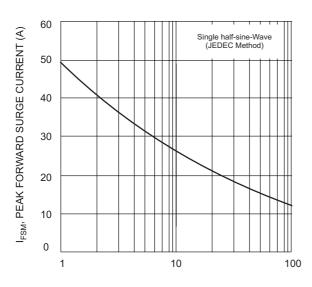
2. Thermal resistance junction to ambient mounted on PC board with 13mm² copper pad.



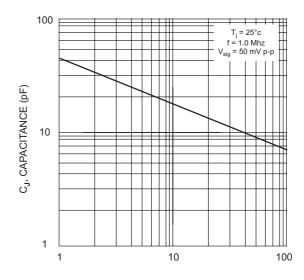
T_A, AMBIENT TEMPERATURE (°C) Fig. 1 Output Current Derating Curve



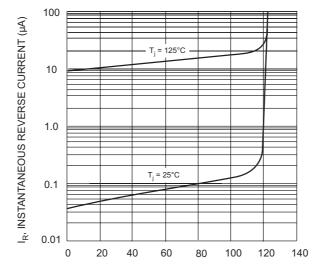
V_F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typ Forward Characteristics (per element)



NUMBER OF CYCLES AT 60 Hz Fig. 3 Max Non-Repetitive Peak Forward Surge Current



 $\label{eq:VR} {\rm V_R,\,REVERSE\,\,VOLTAGE\,\,(V)}$ Fig. 4 Typ Junction Capacitance (per element)



PERCENT OF RATED PEAK REVERSE VOLTAGE (%) Fig. 5 Typ Reverse Characteristics (per element)

ORDERING INFORMATION

Product No.	Package Type	Shipping Quantity			
DF150	DIL Bridge	50 Units/Tube			
DF151	DIL Bridge	50 Units/Tube			
DF152	DIL Bridge	50 Units/Tube			
DF154	DIL Bridge	50 Units/Tube			
DF156	DIL Bridge	50 Units/Tube			
DF158	DIL Bridge	50 Units/Tube			
DF1510	DIL Bridge	50 Units/Tube			

Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.

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WARNING: DO NOT USE IN LIFE SUPPORT EQUIPMENT. WTE power semiconductor products are not authorized for use as critical components in life support devices or systems without the express written approval.

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